

ECENCCE5VB

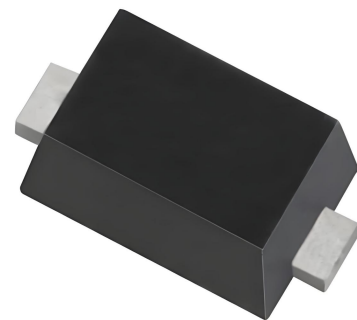
Bidirectional Micro Packaged TVS Diodes for ESD Protection

The ECENCCE5VB is designed to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time provide best in class protection on designs that are exposed to ESD. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space comes at a premium.

It has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by ESD(electrostatic discharge), and EFT (electrical fast transients).

Features

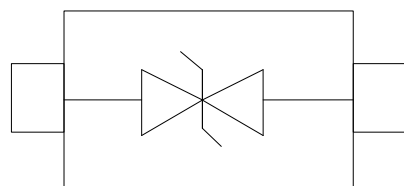
- Peak Power Dissipation – 200 W (8 x 20 us Waveform)
- Replacement for MLV (0603)
- Protects I/O Port
- Low Clamping Voltage
- Low Leakage
- Low Body Height: 1.68mm
- Response Time is < 1 ns
- Stand-off Voltage: 5.0 V
- RoHS Compliant
- Meets MSL 1 Requirements
- Solid-state silicon avalanche technology
- ROHS compliant
- Device Meets MSL 1 Requirements



SOD-523

Main applications

- Cellular handsets and accessories
- Portable instrumentation
- Peripherals
- Serial and Parallel Ports
- Notebooks, Desktops, Servers
- Projection TV



Protection solution to meet

- IEC61000-4-2 (ESD) ±15kV (air), ±8kV (contact)
- IEC61000-4-4 (EFT) 40A (5/50ns)

Ordering Information

Device	Qty per Reel	Reel Size
ECENCCE5VB	3000	7 Inch

Maximum ratings (Tamb=25°C Unless Otherwise Specified)			
Parameter	Symbol	Value	Unit
Peak Pulse Power (tp=8/20μs waveform)	P _{PPP}	120	Watts
ESD Rating per IEC61000-4-2:	Contact	8	KV
	Air	15	
Lead Soldering Temperature	T _L	260 (10 sec.)	°C
Operating Temperature Range	T _J	-55 ~ 150	°C
Storage Temperature Range	T _{STG}	-55 ~ 150	°C
Lead Solder Temperature – Maximum (10 Second Duration)	T _L	260	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

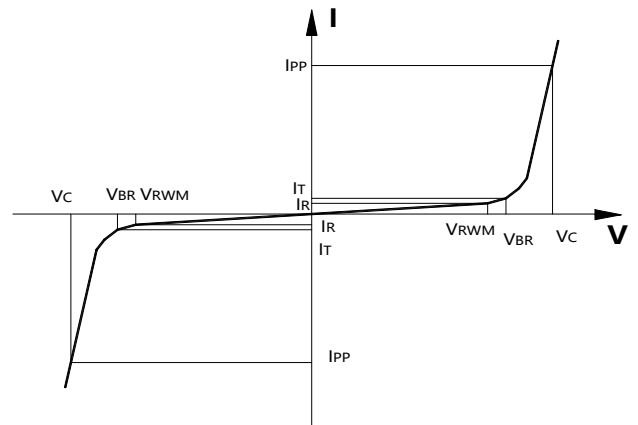
*Other voltages may be available upon request.

1. Non-repetitive current pulse, per Figure 1.

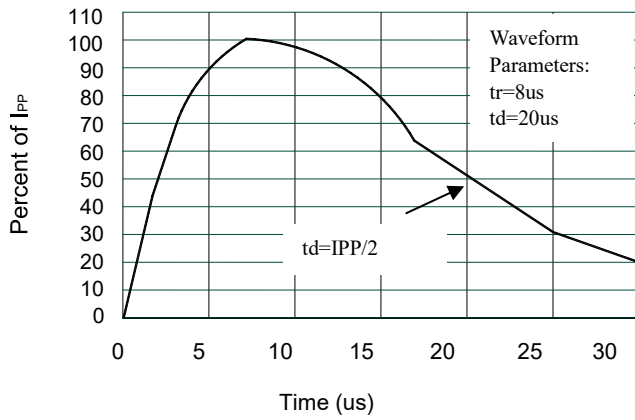
Electrical characteristics (Tamb=25°C Unless Otherwise Specified)						
Device	V _{RWM}	I _R @ V _{RWM}	V _{BR} @ 1 mA	V _C	Capacitance	
			(Volts)	@ 1 A	@ V _R = 0 V, 1 MHz (pF)	
	(V)	(uA)	Min	(V)	Typ	Max
ECENCCE5VB	5.0	2	6.0	9.8	25	40

Junction capacitance is measured in VR=0V,F=1MHz

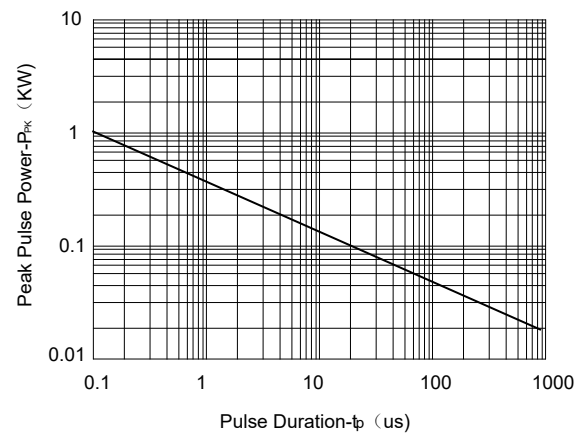
Symbol	Parameter
V _{RWM}	Working Peak Reverse Voltage
V _{BR}	Breakdown Voltage @ I _T
V _C	Clamping Voltage @ I _{PP}
I _T	Test Current
I _{RM}	Leakage current at V _{RWM}
I _{PP}	Peak pulse current
C _O	Off-state Capacitance
C _J	Junction Capacitance



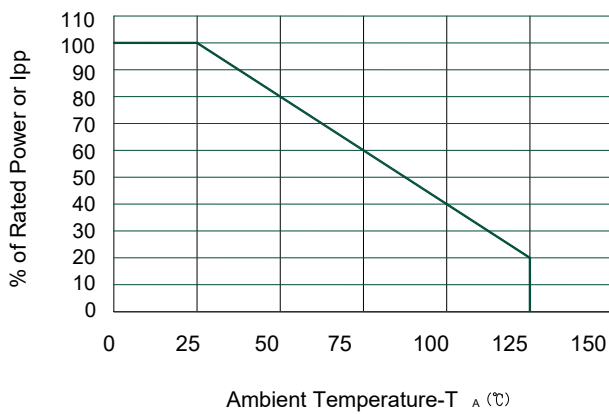
Typical electrical characterist applications



Pulse Waveform



Non-Repetitive Peak Pulse Power vs. Pulse Time



Power Derating Curve

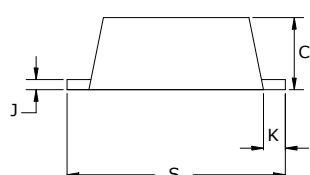
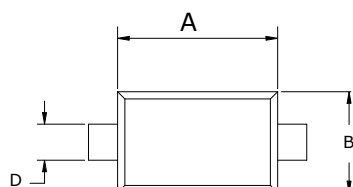
Package Information

SOD-523

Mechanical Data

Case: SOD-523

Case Material: Molded Plastic. UL Flammability



Dim	Millimeters	
	Min	Max
A	1.10	1.30
B	0.75	0.85
C	0.51	0.70
D	0.25	0.35
J	0.08	0.15
K	0.15	0.25
S	1.50	1.70

Recommended Pad outline

